Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
0.150 inches
Overall Diameter:
0.067 inches
Mounting Method:
Press fit
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
35.0 reverse voltage, dc
Current Rating Per Characteristic:
10.00 microamperes forward current, average peak
Capacitance Rating In Picofarads:
1.2
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
No
Fiig:
A110a0